SK 80 D 12 F



SEMITOP[®] 3

Bridge Rectifier

SK 80 D 12 F

Preliminary Data

Features

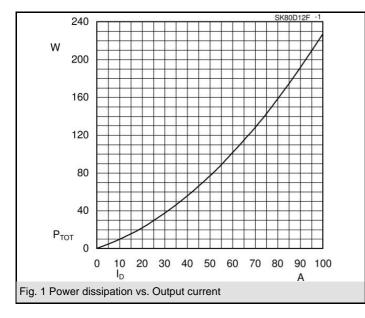
- Compact design
- One screw mounting
- Heat transfer and insulation through direct copper bonded aluminium oxide ceramic (DCB
- Fast and soft recovery CAL (Controlled Axial Lifetime) diode
- UL recognized, file no. E 63 532

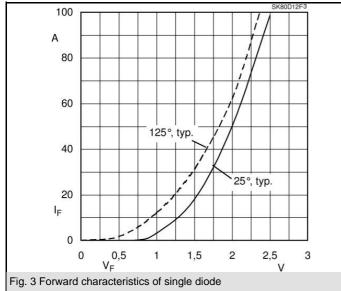
Typical Applications*

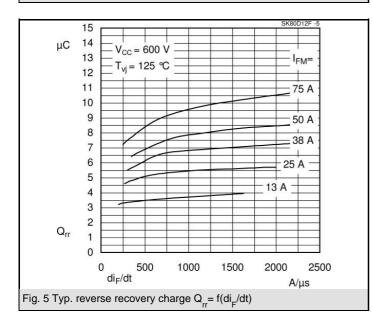
- General power switching applications
- UPS
- SMPS

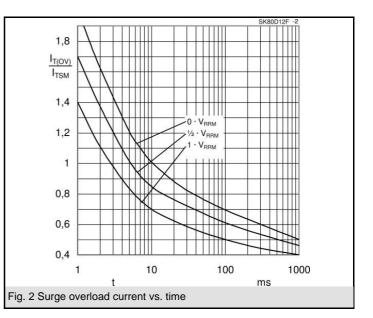
V _{RSM} V		V _{RRM} , V _{DRM}		I _D = 80 A (full conduction)	
		V		(T _s = 80 °C)	
		1200		SK 80 D 12 F	
Symbol	Con	ditions		Values	Units
I _D		80 °C		80	А
I _{RRM}		125°C (See Fig. 6)		typ. 40	А
Q _{rr}	$T_{vj} = 2$	25 (125)°C (See Fig. 6	6)	typ. 3 (8)	μC
I _R	$T_{vi} = 2$	25 (150)°C; V _R =V _{RRM}		0,2 (4)	mA
I _{FSM}	T _{vi} =	150 °C; 10 ms		550	A
		°C; ms			А
i²t	$T_{vi} =$	150 °C; 10 ms		1500	A²s
	T _{vi} =	°C; ms			A²s
V _F	T _{vi} =	25 °C; I _F = 75 A		max. 2,5	V
V _(TO)		125 °C		max. 1,2	V
r _T		125 °C		max. 22	mΩ
I _{RD}	$T_{vj} =$	°C; V_{DD} = V_{DRM} ; V_{RD}	= V _{RRM}		mA
					mA
R _{th(j-s)}	per d	liode		0,9	K/W
un(-3)	per n	nodule		0,15	K/W
T _{solder}	termi	nals, 10s		260	°C
T _{vi}				-40+150	°C
T _{stg}				-40+125	°C
V _{isol}	a. c.	a. c. 50 Hz; r.m.s.; 1 s / 1 min.		3000 (2500)	V
Ms	mounting torque to heatsink		2,5	Nm	
M _t					
m	approx. weight		30	g	
Case	e SEMITOP [®] 3		T 25		

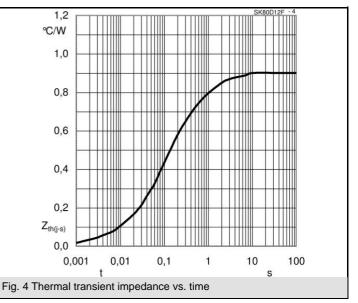
SK 80 D 12 F

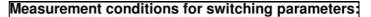






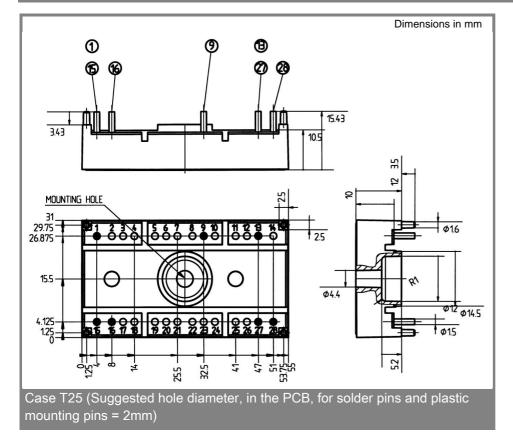


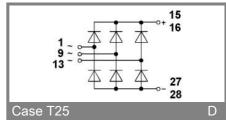




I_F= 50A V_R= 600V -di/dt = 800A/μs ^{Fig. 6}

SK 80 D 12 F





* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.